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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, SD, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I ² S, LVD, POR, PWM, WDT
Number of I/O	100
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 2x16b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mk66fn2m0vlq18r

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1 Ratings

1.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T _{STG}	Storage temperature	−55	150	°C	1
T _{SDR}	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

1.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

1.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	−2000	+2000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model	−500	+500	V	2
I _{LAT}	Latch-up current at ambient temperature of 105°C	−100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

1.4 Voltage and current operating ratings

Table 6. Low power mode peripheral adders — typical value (continued)

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
$I_{\text{IREFSTEN32KHz}}$	32 kHz internal reference clock (IRC) adder. Measured by entering STOP mode with the 32 kHz IRC enabled.	52	52	52	52	52	52	μA
$I_{\text{IREFSTEN4MHz}}$	External 4 MHz crystal clock adder. Measured by entering STOP or VLPS mode with the crystal enabled.	206	228	237	245	251	258	μA
$I_{\text{IREFSTEN32KHz}}$	External 32 kHz crystal clock adder by means of the OSC0_CR[EREFSSTEN and EREFSTEN] bits. Measured by entering all modes with the crystal enabled.							nA
	VLLS1	440	490	540	560	570	580	
	VLLS3	440	490	540	560	570	580	
	LLS2	490	490	540	560	570	680	
	LLS3	490	490	540	560	570	680	
	VLPS	510	560	560	560	610	680	
	STOP	510	560	560	560	610	680	
$I_{48\text{MIRC}}$	48MHz IRC	511	520	545	556	563	576	μA
I_{CMP}	CMP peripheral adder measured by placing the device in VLLS1 mode with CMP enabled using the 6-bit DAC and a single external input for compare. Includes 6-bit DAC power consumption.	22	22	22	22	22	22	μA
I_{RTC}	RTC peripheral adder measured by placing the device in VLLS1 mode with external 32 kHz crystal enabled by means of the RTC_CR[OSCE] bit and the RTC ALARM set for 1 minute. Includes ERCLK32K (32 kHz external crystal) power consumption.	432	357	388	475	532	810	nA
I_{UART}	UART peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source waiting for RX data at 115200 baud rate. Includes selected clock source power consumption.							μA
	MCGIRCLK (4 MHz internal reference clock)	66	66	66	66	66	66	
	OSCERCLK (4 MHz external crystal)	214	234	246	254	260	268	
I_{BG}	Bandgap adder when BGEN bit is set and device is placed in VLPx, LLS, or VLLSx mode.	45	45	45	45	45	45	μA
I_{ADC}	ADC peripheral adder combining the measured values at V_{DD} and V_{DDA} by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions.	366	366	366	366	366	366	μA

Table 7. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I _{DD_WAIT}	Wait mode reduced frequency current at 3.0 V — all peripheral clocks enabled	—	35	62.81	mA	8
I _{DD_VLPR}	Very-low-power run mode current at 3.0 V — all peripheral clocks disabled	—	1.1	9.56	mA	9
I _{DD_VLPR}	Very-low-power run mode current at 3.0 V — all peripheral clocks enabled	—	2	9.88	mA	10
I _{DD_VLPRC} O	Very-low-power run mode current in compute operation - 4 MHz core / 1 MHz flash / bus clock disabled, LPTMR running with 4 MHz internal reference clock at 3.0 V	—	986	9.47	μA	11
I _{DD_VLPW}	Very-low-power wait mode current at 3.0 V — all peripheral clocks disabled	—	0.690	9.25	mA	12
I _{DD_VLPW}	Very-low-power wait mode current at 3.0 V — all peripheral clocks enabled	—	1.5	10.00	mA	
I _{DD_STOP}	Stop mode current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	0.791 3.8 13.2	2.39 6.91 18.91	mA mA mA	
I _{DD_VLPS}	Very-low-power stop mode current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	202 1400 5100	353.77 2464.54 8949.06	μA μA μA	
I _{DD_LLS3}	Low leakage stop mode current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	9.0 76.3 402	16.5 88.63 656.08	μA μA μA	
I _{DD_LLS2}	Low leakage stop mode current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	5.7 41.3 229	9.7 55.80 276.81	μA μA μA	
I _{DD_VLLS3}	Very low-leakage stop mode 3 current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	5.5 46.3 249	7.31 58.33 380.77	μA μA μA	
I _{DD_VLLS2}	Very low-leakage stop mode 2 current at 3.0 V @ -40 to 25°C @ 70°C @ 105°C	— — —	2.7 13.1 76.6	3.24 18.72 84.77	μA μA μA	

Table continues on the next page...

3.3.2 IRC48M specifications

Table 17. IRC48M specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{DD}	Supply voltage	1.71	—	3.6	V	
I _{DD48M}	Supply current	—	520	—	μA	
f _{irc48m}	Internal reference frequency	—	48	—	MHz	
Δf _{irc48m_ol_lv}	Open loop total deviation of IRC48M frequency at low voltage (VDD=1.71V-1.89V) over full temperature - Regulator disable (USB_CLK_RECOVER_IRC_EN[REG_EN]=0) - Regulator enable (USB_CLK_RECOVER_IRC_EN[REG_EN]=1)	— —	± 0.4 ± 0.5	± 1.0 ± 1.5	%f _{irc48m}	1
Δf _{irc48m_ol_hv}	Open loop total deviation of IRC48M frequency at high voltage (VDD=1.89V-3.6V) over 0—70°C Regulator enable (USB_CLK_RECOVER_IRC_EN[REG_EN]=1)	—	± 0.2	± 0.5	%f _{irc48m}	1
Δf _{irc48m_ol_hv}	Open loop total deviation of IRC48M frequency at high voltage (VDD=1.89V-3.6V) over full temperature Regulator enable (USB_CLK_RECOVER_IRC_EN[REG_EN]=1)	—	± 0.4	± 1.0	%f _{irc48m}	1
Δf _{irc48m_cl}	Closed loop total deviation of IRC48M frequency over voltage and temperature	—	—	± 0.1	%f _{host}	2
J _{cyc_irc48m}	Period Jitter (RMS)	—	35	150	ps	
t _{irc48mst}	Startup time	—	2	3	μs	3

1. The maximum value represents characterized results equivalent to mean plus or minus three times the standard deviation (mean ± 3 sigma)
2. Closed loop operation of the IRC48M is only feasible for USB device operation; it is not usable for USB host operation. It is enabled by configuring for USB Device, selecting IRC48M as USB clock source, and enabling the clock recover function (USB_CLK_RECOVER_IRC_CTRL[CLOCK_RECOVER_EN]=1, USB_CLK_RECOVER_IRC_EN[IRC_EN]=1).
3. IRC48M startup time is defined as the time between clock enablement and clock availability for system use. Enable the clock by one of the following settings:
 - USB_CLK_RECOVER_IRC_EN[IRC_EN]=1, or
 - MCG_C7[OSCSEL]=10, or
 - SIM_SOPT2[PLLFLSEL]=11

3.3.3 Oscillator electrical specifications

- Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S register being set.

NOTE

The 32 kHz oscillator works in low power mode by default and cannot be moved into high power/gain mode.

3.3.4 32 kHz oscillator electrical characteristics

3.3.4.1 32 kHz oscillator DC electrical specifications

Table 20. 32kHz oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V_{BAT}	Supply voltage	1.71	—	3.6	V
R_F	Internal feedback resistor	—	100	—	$M\Omega$
C_{para}	Parasitical capacitance of EXTAL32 and XTAL32	—	5	7	pF
V_{pp} ¹	Peak-to-peak amplitude of oscillation	—	0.6	—	V

- When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

3.3.4.2 32 kHz oscillator frequency specifications

Table 21. 32 kHz oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{osc_lo}	Oscillator crystal	—	32.768	—	kHz	
t_{start}	Crystal start-up time	—	1000	—	ms	1
$f_{ec_extal32}$	Externally provided input clock frequency	—	32.768	—	kHz	2
$V_{ec_extal32}$	Externally provided input clock amplitude	700	—	V_{BAT}	mV	2, 3

- Proper PC board layout procedures must be followed to achieve specifications.
- This specification is for an externally supplied clock driven to EXTAL32 and does not apply to any other clock input. The oscillator remains enabled and XTAL32 must be left unconnected.
- The parameter specified is a peak-to-peak value and V_{IH} and V_{IL} specifications do not apply. The voltage of the applied clock must be within the range of V_{SS} to V_{BAT} .

3.4 Memories and memory interfaces

Table 23. Flash command timing specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t_{vfykey}	Verify Backdoor Access Key execution time	—	—	30	μs	1
t_{swapx01}	Swap Control execution time	—	200	—	μs	
t_{swapx02}	• control code 0x02	—	90	150	μs	
t_{swapx04}	• control code 0x04	—	90	150	μs	
t_{swapx08}	• control code 0x08	—	—	30	μs	
t_{swapx10}	• control code 0x10	—	90	150	μs	
$t_{\text{pgmpart32k}}$	Program Partition for EEPROM execution time	—	70	—	ms	
$t_{\text{pgmpart256k}}$	• 32 KB EEPROM backup	—	78	—	ms	
	• 256 KB EEPROM backup	—	—	—	ms	
t_{setramff}	Set FlexRAM Function execution time:	—	70	—	μs	
$t_{\text{setram32k}}$	• Control Code 0xFF	—	0.8	1.2	ms	
$t_{\text{setram64k}}$	• 32 KB EEPROM backup	—	1.3	1.9	ms	
$t_{\text{setram128k}}$	• 64 KB EEPROM backup	—	2.4	3.1	ms	
$t_{\text{setram256k}}$	• 128 KB EEPROM backup	—	4.5	5.5	ms	
$t_{\text{eewr8b32k}}$	Byte-write to FlexRAM execution time:	—	385	1700	μs	
$t_{\text{eewr8b64k}}$	• 32 KB EEPROM backup	—	475	2000	μs	
$t_{\text{eewr8b128k}}$	• 64 KB EEPROM backup	—	650	2350	μs	
$t_{\text{eewr8b256k}}$	• 128 KB EEPROM backup	—	1000	3250	μs	
$t_{\text{eewr16b32k}}$	16-bit write to FlexRAM execution time:	—	385	1700	μs	
$t_{\text{eewr16b64k}}$	• 32 KB EEPROM backup	—	475	2000	μs	
$t_{\text{eewr16b128k}}$	• 64 KB EEPROM backup	—	650	2350	μs	
$t_{\text{eewr16b256k}}$	• 128 KB EEPROM backup	—	1000	3250	μs	
$t_{\text{eewr32bers}}$	32-bit write to erased FlexRAM location execution time	—	360	1500	μs	
$t_{\text{eewr32b32k}}$	32-bit write to FlexRAM execution time:	—	630	2000	μs	
$t_{\text{eewr32b64k}}$	• 32 KB EEPROM backup	—	810	2250	μs	
$t_{\text{eewr32b128k}}$	• 64 KB EEPROM backup	—	1200	2650	μs	
$t_{\text{eewr32b256k}}$	• 128 KB EEPROM backup	—	1900	3500	μs	
	• 256 KB EEPROM backup	—	—	—	μs	

1. Assumes 25MHz or greater flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.

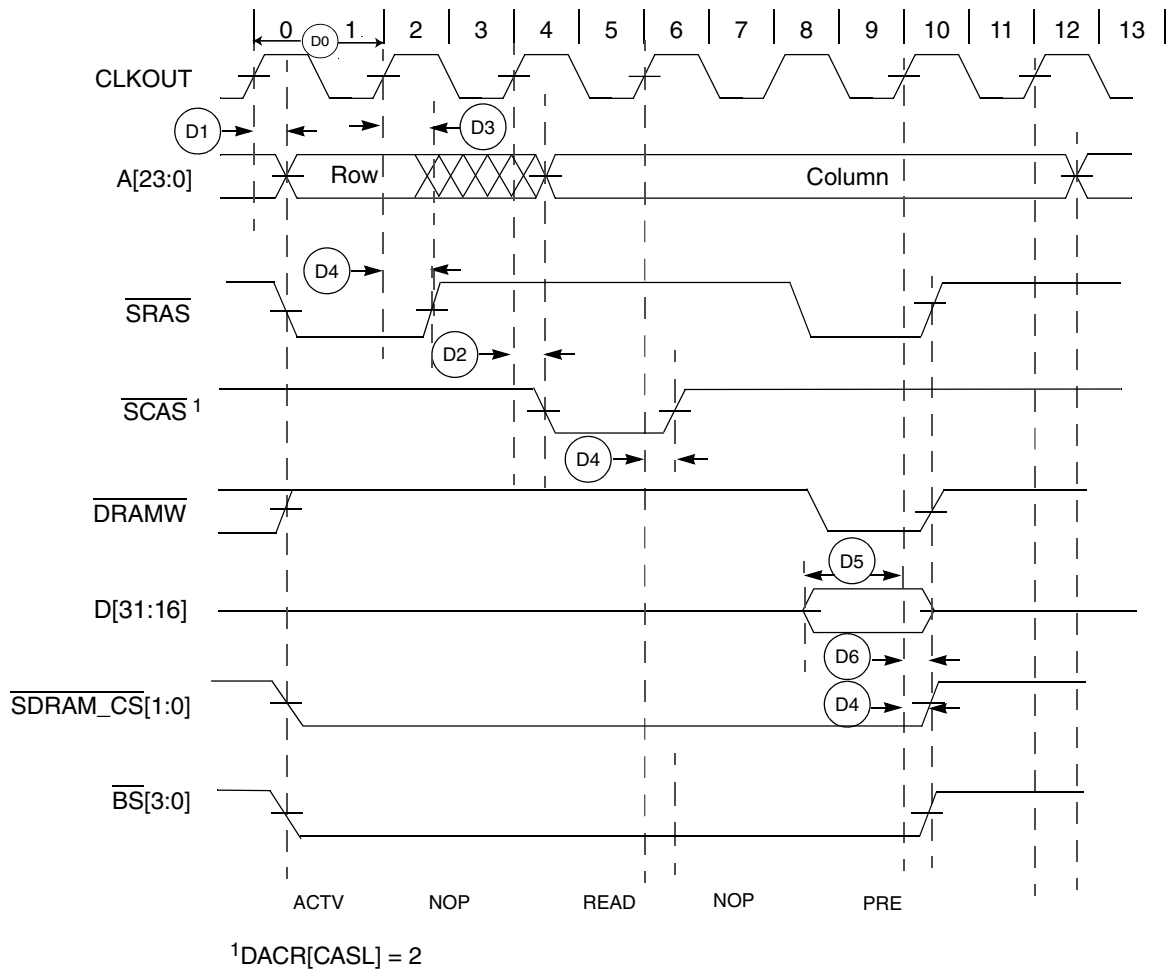


Figure 15. SDRAM read timing diagram

Table 29. SDRAM Timing (Full voltage range)

NUM	Characteristic ¹	Symbol	Min	Max	Unit
	Operating voltage	1.71	3.6	V	
	Frequency of operation	—	CLKOUT	MHz	
D0	Clock period	1/CLKOUT	—	ns	²
D1	CLKOUT high to SDRAM address valid	t_{CHDAV}	-	11.2	ns
D2	CLKOUT high to SDRAM control valid	t_{CHDCV}		11.1	ns
D3	CLKOUT high to SDRAM address invalid	t_{CHDAI}	1.0	-	ns
D4	CLKOUT high to SDRAM control invalid	t_{CHDCI}	1.0	-	ns
D5	SDRAM data valid to CLKOUT high	t_{DDVCH}	12.0	-	ns
D6	CLKOUT high to SDRAM data invalid	t_{CHDDI}	1.0	-	ns
D7 ³	CLKOUT high to SDRAM data valid	t_{CHDDVW}	-	12.0	ns
D8 ³	CLKOUT high to SDRAM data invalid	t_{CHDDIW}	1.0	-	ns

1. All timing specifications are based on taking into account, a 25pF load on the SDRAM output pins.

2. CLKOUT is same as FB_CLK, maximum frequency can be 60 MHz

4. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

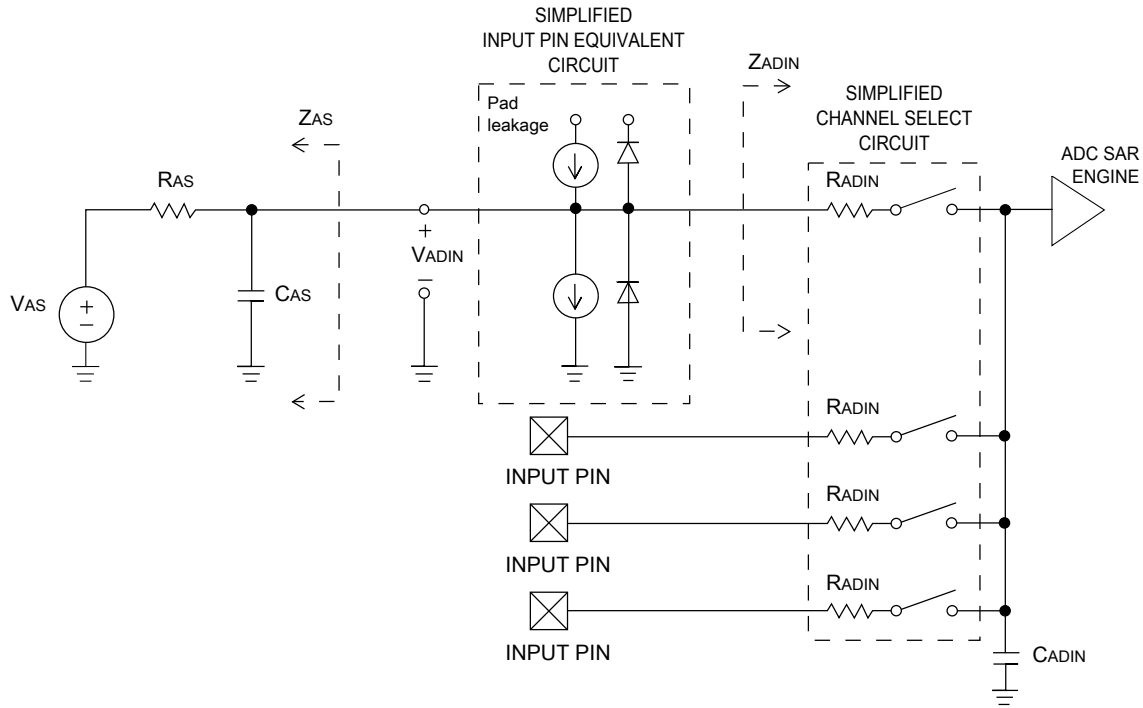


Figure 17. ADC input impedance equivalency diagram

3.6.1.2 16-bit ADC electrical characteristics

Table 32. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	- ADLPC = 1, ADHSC = 0 - ADLPC = 1, ADHSC = 1 - ADLPC = 0, ADHSC = 0 - ADLPC = 0, ADHSC = 1	1.2 2.4 3.0 4.4	2.4 4.0 5.2 6.2	3.9 6.1 7.3 9.5	MHz MHz MHz MHz	$t_{ADACK} = 1/f_{ADACK}$
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	12-bit modes <12-bit modes	— —	±4 ±1.4	±6.8 ±2.1	LSB ⁴	5
DNL	Differential non-linearity	12-bit modes <12-bit modes	— —	±0.7 ±0.2	–1.1 to +1.9 –0.3 to 0.5	LSB ⁴	5

Table continues on the next page...

Peripheral operating requirements and behaviors

6. $V_{DDA} = 3.0\text{ V}$, reference select set for V_{DDA} (DACx_CO:DACRFS = 1), high power mode (DACx_C0:LPEN = 0), DAC set to 0x800, temperature range is across the full range of the device

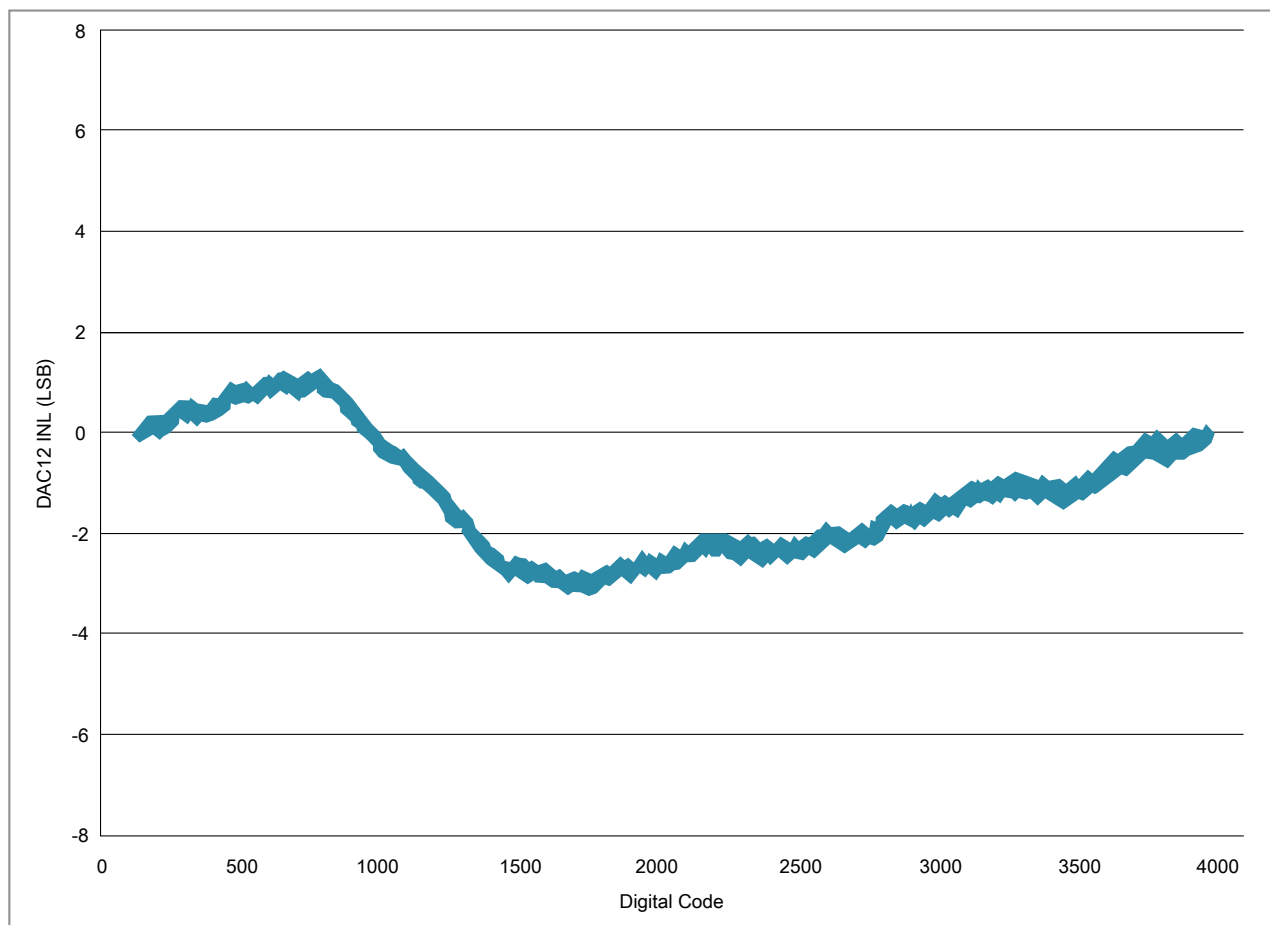


Figure 22. Typical INL error vs. digital code

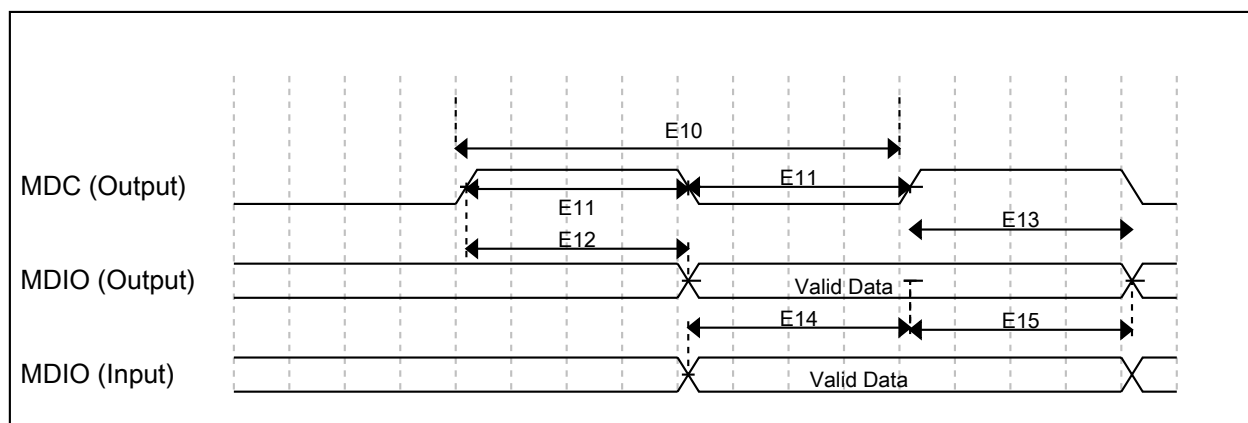


Figure 26. MDIO serial management channel timing diagram

3.8.2 USB Voltage Regulator Electrical Specifications

Table 45. USB VREG electrical specifications

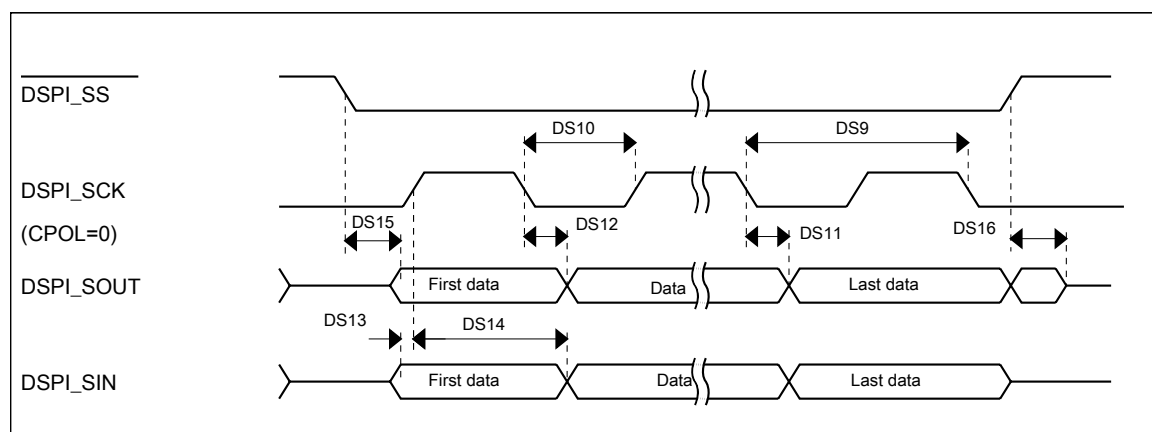
Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
VREG_IN0 VREG_IN1	Regulator selectable input supply voltages	2.7	—	5.5	V	2
I _{DDon} VREG_IN0 VREG_IN1	Quiescent current — Run mode, load current equal zero, input supply (VREG_IN*) > 3.6 V	— —	157 157	— —	μA	
I _{DDstby} VREG_IN0 VREG_IN1	Quiescent current — Standby mode, load current equal zero	— —	2 2	— —	μA	
I _{DDoff} VREG_IN0 VREG_IN1	Quiescent current — Shutdown mode • VREG_IN* = 5.0 V and temperature = 25 °C	— —	680 920	— —	nA	
I _{LOADrun}	Maximum load current — Run mode	—	—	150	mA	3
I _{LOADstby}	Maximum load current — Standby mode	—	—	1	mA	
V _{DROPOUT}	Regulator drop-out voltage — Run mode at maximum load current with inrush current limit disabled	300	—	—	mV	
VREG_OUT	Regulator programmable output target voltage — Selected input supply > programmed output target voltage + V _{DROPOUT} • Run mode • Standby mode	3 2.1	3.3 2.8	3.6 3.6	V V	4

Table continues on the next page...

Table 48. Slave mode DSPI timing (limited voltage range) (continued)

Num	Description	Min.	Max.	Unit
DS9	DSPI_SCK input cycle time	$4 \times t_{BUS}$	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	23.0	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2.7	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7.0	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	13	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	13	ns

1. The maximum operating frequency is measured with non-continuous CS and SCK. When DSPI is configured with continuous CS and SCK, there is a constraint that SPI clock should not be greater than 1/6 of bus clock, for example, when bus clock is 60MHz, SPI clock should not be greater than 10MHz.

**Figure 28. DSPI classic SPI timing — slave mode**

3.8.7 DSPI switching specifications (full voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 49. Master mode DSPI timing (full voltage range)

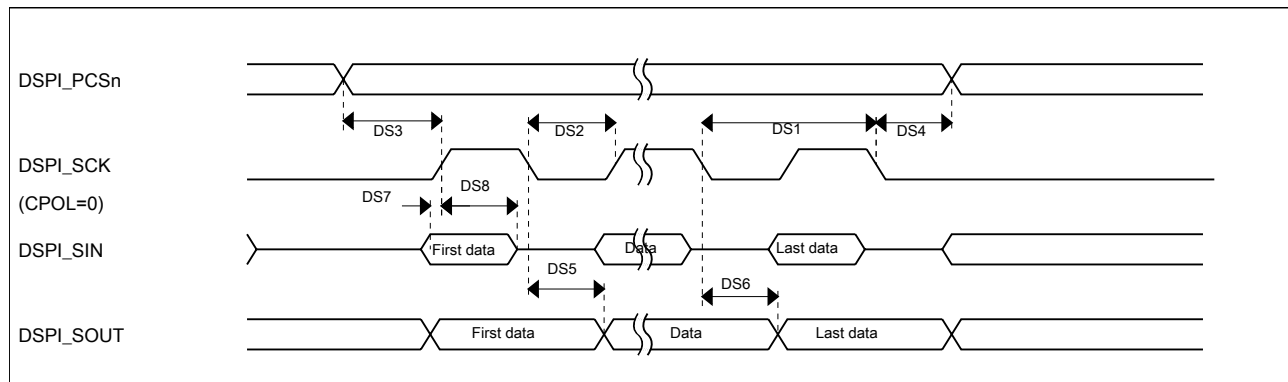
Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	1
	Frequency of operation	—	15	MHz	

Table continues on the next page...

Table 49. Master mode DSPI timing (full voltage range) (continued)

Num	Description	Min.	Max.	Unit	Notes
DS1	DSPI_SCK output cycle time	$4 \times t_{\text{BUS}}$	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{\text{SCK}}/2) - 4$	$(t_{\text{SCK}}/2) + 4$	ns	
DS3	DSPI_PCSn valid to DSPI_SCK delay	$(t_{\text{BUS}} \times 2) - 4$	—	ns	2
DS4	DSPI_SCK to DSPI_PCSn invalid delay	$(t_{\text{BUS}} \times 2) - 4$	—	ns	3
DS5	DSPI_SCK to DSPI_SOUT valid	—	15	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	1.0	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	15.8	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The DSPI module can operate across the entire operating voltage for the processor, but to run across the full voltage range the maximum frequency of operation is reduced.
2. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].
3. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].

**Figure 29. DSPI classic SPI timing — master mode****Table 50. Slave mode DSPI timing (full voltage range)**

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
	Frequency of operation	—	7.5	MHz
DS9	DSPI_SCK input cycle time	$8 \times t_{\text{BUS}}$	—	ns
DS10	DSPI_SCK input high/low time	$(t_{\text{SCK}}/2) - 4$	$(t_{\text{SCK}}/2) + 4$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	23.1	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2.6	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7.0	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	13.0	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	13.0	ns

3.8.10 Low Power UART switching specifications

See [General switching specifications](#).

3.8.11 SDHC specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

Table 53. SDHC full voltage range switching specifications

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	1.71	3.6	V
Card input clock					
SD1	fpp	Clock frequency (low speed)	0	400	kHz
	fpp	Clock frequency (SD\SDIO full speed\high speed)	0	25\50	MHz
	fpp	Clock frequency (MMC full speed\high speed)	0	20\50	MHz
	f _{OD}	Clock frequency (identification mode)	0	400	kHz
SD2	t _{WL}	Clock low time	7	—	ns
SD3	t _{WH}	Clock high time	7	—	ns
SD4	t _{TLH}	Clock rise time	—	3	ns
SD5	t _{THL}	Clock fall time	—	3	ns
SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD6	t _{OD}	SDHC output delay (output valid)	-5	8.6 8.3	ns
SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD7	t _{ISU}	SDHC input setup time	5	—	ns
SD8	t _{IH}	SDHC input hold time	0	—	ns

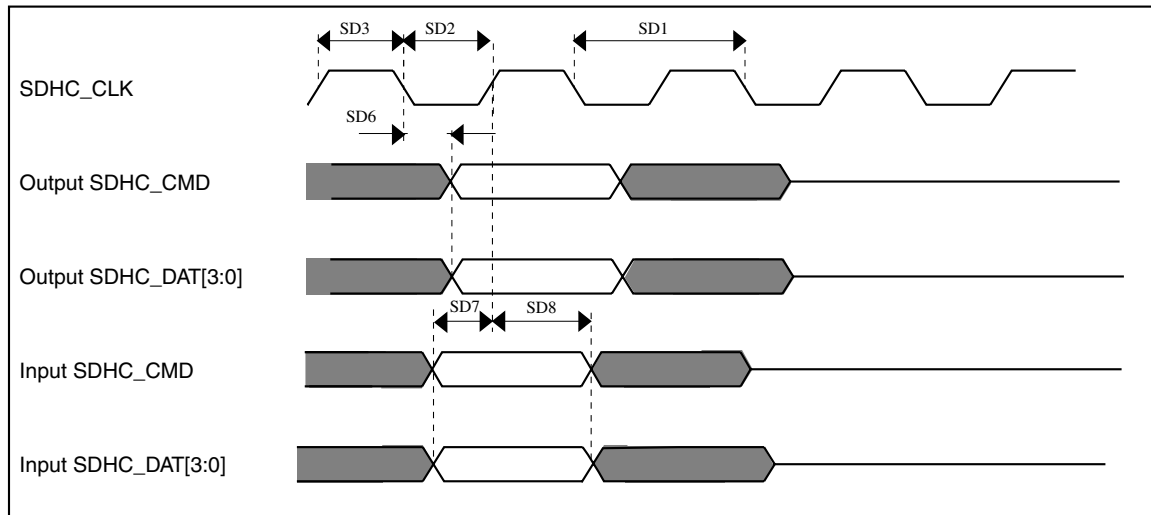
Table 54. SDHC limited voltage range switching specifications

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	2.7	3.6	V
Card input clock					
SD1	fpp	Clock frequency (low speed)	0	400	kHz
	fpp	Clock frequency (SD\SDIO full speed\high speed)	0	25\50	MHz
	fpp	Clock frequency (MMC full speed\high speed)	0	20\50	MHz
	f _{OD}	Clock frequency (identification mode)	0	400	kHz
SD2	t _{WL}	Clock low time	7	—	ns
SD3	t _{WH}	Clock high time	7	—	ns
SD4	t _{TLH}	Clock rise time	—	3	ns
SD5	t _{THL}	Clock fall time	—	3	ns

Table continues on the next page...

Table 54. SDHC limited voltage range switching specifications (continued)

Num	Symbol	Description	Min.	Max.	Unit
SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD6	t_{OD}	SDHC output delay (output valid)	-5	7.6 8.3	ns
SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD7	t_{ISU}	SDHC input setup time	5	—	ns
SD8	t_{IH}	SDHC input hold time	0	—	ns

**Figure 32. SDHC timing**

3.8.12 I²S switching specifications

This section provides the AC timings for the I²S in master (clocks driven) and slave modes (clocks input). All timings are given for non-inverted serial clock polarity (TCR[TSCKP] = 0, RCR[RSCKP] = 0) and a non-inverted frame sync (TCR[TFISI] = 0, RCR[RFSI] = 0). If the polarity of the clock and/or the frame sync have been inverted, all the timings remain valid by inverting the clock signal (I2S_BCLK) and/or the frame sync (I2S_FS) shown in the figures below.

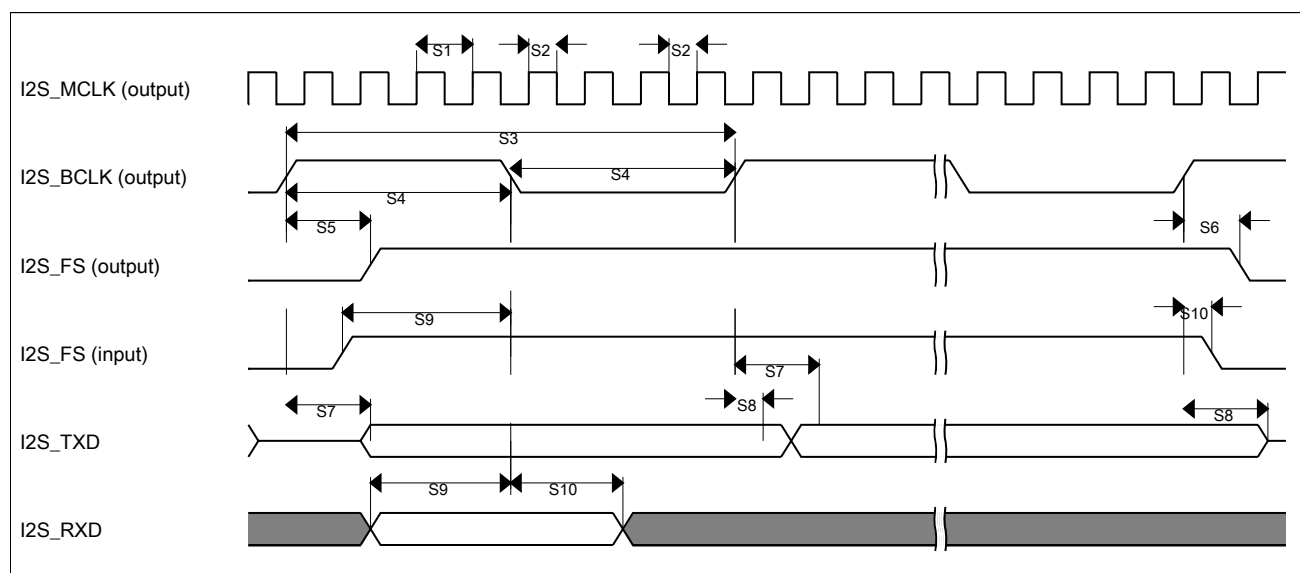
Table 55. I2S master mode timing (limited voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_BCLK cycle time	80	—	ns

Table continues on the next page...

Table 55. I2S master mode timing (limited voltage range) (continued)

Num	Description	Min.	Max.	Unit
S4	I2S_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_BCLK to I2S_FS output valid	—	15	ns
S6	I2S_BCLK to I2S_FS output invalid	0	—	ns
S7	I2S_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_FS input setup before I2S_BCLK	15	—	ns
S10	I2S_RXD/I2S_FS input hold after I2S_BCLK	0	—	ns

**Figure 33. I2S timing — master mode****Table 56. I2S slave mode timing (limited voltage range)**

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S11	I2S_BCLK cycle time (input)	80	—	ns
S12	I2S_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_FS input setup before I2S_BCLK	4.5	—	ns
S14	I2S_FS input hold after I2S_BCLK	2	—	ns
S15	I2S_BCLK to I2S_TXD/I2S_FS output valid	—	20	ns
S16	I2S_BCLK to I2S_TXD/I2S_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_BCLK	4.5	—	ns
S18	I2S_RXD hold after I2S_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹		25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

Pinout

144 LQFP	144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
38	L3	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23								
39	L4	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23								
40	M7	XTAL32	XTAL32	XTAL32								
41	M6	EXTAL32	EXTAL32	EXTAL32								
42	L6	VBAT	VBAT	VBAT								
43	—	VDD	VDD	VDD								
44	—	VSS	VSS	VSS								
45	M4	PTE24	ADC0_SE17	ADC0_SE17	PTE24	CAN1_TX	UART4_TX		I2C0_SCL	EWM_OUT_ b		
46	K5	PTE25/ LLWU_P21	ADC0_SE18	ADC0_SE18	PTE25/ LLWU_P21	CAN1_RX	UART4_RX		I2C0_SDA	EWM_IN		
47	K4	PTE26	DISABLED		PTE26	ENET_1588_ CLKIN	UART4_ CTS_b			RTC_ CLKOUT	USB0_CLKIN	
48	J4	PTE27	DISABLED		PTE27		UART4_ RTS_b					
49	H4	PTE28	DISABLED		PTE28							
50	J5	PTA0	JTAG_TCLK/ SWD_CLK/ EZP_CLK	TSIO_CH1	PTA0	UART0_ CTS_b/ UART0_ COL_b	FTM0_CH5		LPUART0_ CTS_b		JTAG_TCLK/ SWD_CLK	EZP_CLK
51	J6	PTA1	JTAG_TDI/ EZP_DI	TSIO_CH2	PTA1	UART0_RX	FTM0_CH6	I2C3_SDA	LPUART0_ RX		JTAG_TDI	EZP_DI
52	K6	PTA2	JTAG_TDO/ TRACE_ SWO/ EZP_DO	TSIO_CH3	PTA2	UART0_TX	FTM0_CH7	I2C3_SCL	LPUART0_ TX		JTAG_TDO/ TRACE_ SWO	EZP_DO
53	K7	PTA3	JTAG_TMS/ SWD_DIO	TSIO_CH4	PTA3	UART0_ RTS_b	FTM0_CH0		LPUART0_ RTS_b		JTAG_TMS/ SWD_DIO	
54	L7	PTA4/ LLWU_P3	NMI_b/ EZP_CS_b	TSIO_CH5	PTA4/ LLWU_P3		FTM0_CH1				NMI_b	EZP_CS_b
55	M8	PTA5	DISABLED		PTA5	USB0_CLKIN	FTM0_CH2	RMII0_ RXER/ MII0_RXER	CMP2_OUT	I2S0_TX_ BCLK	JTAG_ TRST_b	
56	E7	VDD	VDD	VDD								
57	G7	VSS	VSS	VSS								
58	J7	PTA6	DISABLED		PTA6		FTM0_CH3		CLKOUT		TRACE_ CLKOUT	
59	J8	PTA7	ADC0_SE10	ADC0_SE10	PTA7		FTM0_CH4		RMII0_MDIO/ MII0_MDIO		TRACE_D3	

Pinout

144 LQFP	144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
82	H9	PTB1	ADC0_SE9/ ADC1_SE9/ TSIO_CH6	ADC0_SE9/ ADC1_SE9/ TSIO_CH6	PTB1	I2C0_SDA	FTM1_CH1	RMII0_MDC/ MII0_MDC	SDRAM_ RAS_b	FTM1_QD_ PHB/ TPM1_CH1		
83	G12	PTB2	ADC0_SE12/ TSIO_CH7	ADC0_SE12/ TSIO_CH7	PTB2	I2C0_SCL	UART0_ RTS_b	ENET0_ 1588_TMR0	SDRAM_WE	FTM0_FLT3		
84	G11	PTB3	ADC0_SE13/ TSIO_CH8	ADC0_SE13/ TSIO_CH8	PTB3	I2C0_SDA	UART0_ CTS_b/ UART0_ COL_b	ENET0_ 1588_TMR1	SDRAM_ CS0_b	FTM0_FLT0		
85	G10	PTB4	ADC1_SE10	ADC1_SE10	PTB4			ENET0_ 1588_TMR2	SDRAM_ CS1_b	FTM1_FLT0		
86	G9	PTB5	ADC1_SE11	ADC1_SE11	PTB5			ENET0_ 1588_TMR3		FTM2_FLT0		
87	F12	PTB6	ADC1_SE12	ADC1_SE12	PTB6				FB_AD23/ SDRAM_D23			
88	F11	PTB7	ADC1_SE13	ADC1_SE13	PTB7				FB_AD22/ SDRAM_D22			
89	F10	PTB8	DISABLED		PTB8		UART3_ RTS_b		FB_AD21/ SDRAM_D21			
90	F9	PTB9	DISABLED		PTB9	SPI1_PCS1	UART3_ CTS_b		FB_AD20/ SDRAM_D20			
91	E12	PTB10	ADC1_SE14	ADC1_SE14	PTB10	SPI1_PCS0	UART3_RX		FB_AD19/ SDRAM_D19	FTM0_FLT1		
92	E11	PTB11	ADC1_SE15	ADC1_SE15	PTB11	SPI1_SCK	UART3_TX		FB_AD18/ SDRAM_D18	FTM0_FLT2		
93	H7	VSS	VSS	VSS								
94	F5	VDD	VDD	VDD								
95	E10	PTB16	TSIO_CH9	TSIO_CH9	PTB16	SPI1_SOUT	UART0_RX	FTM_CLKIN0	FB_AD17/ SDRAM_D17	EWM_IN	TPM_ CLKIN0	
96	E9	PTB17	TSIO_CH10	TSIO_CH10	PTB17	SPI1_SIN	UART0_TX	FTM_CLKIN1	FB_AD16/ SDRAM_D16	EWM_OUT_ b	TPM_ CLKIN1	
97	D12	PTB18	TSIO_CH11	TSIO_CH11	PTB18	CAN0_TX	FTM2_CH0	I2S0_TX_ BCLK	FB_AD15/ SDRAM_A23	FTM2_QD_ PHA/ TPM2_CH0		
98	D11	PTB19	TSIO_CH12	TSIO_CH12	PTB19	CAN0_RX	FTM2_CH1	I2S0_TX_FS	FB_OE_b	FTM2_QD_ PHB/ TPM2_CH1		
99	D10	PTB20	DISABLED		PTB20	SPI2_PCS0			FB_AD31/ SDRAM_D31	CMP0_OUT		
100	D9	PTB21	DISABLED		PTB21	SPI2_SCK			FB_AD30/ SDRAM_D30	CMP1_OUT		
101	C12	PTB22	DISABLED		PTB22	SPI2_SOUT			FB_AD29/ SDRAM_D29	CMP2_OUT		
102	C11	PTB23	DISABLED		PTB23	SPI2_SIN	SPI0_PCS5		FB_AD28/ SDRAM_D28	CMP3_OUT		

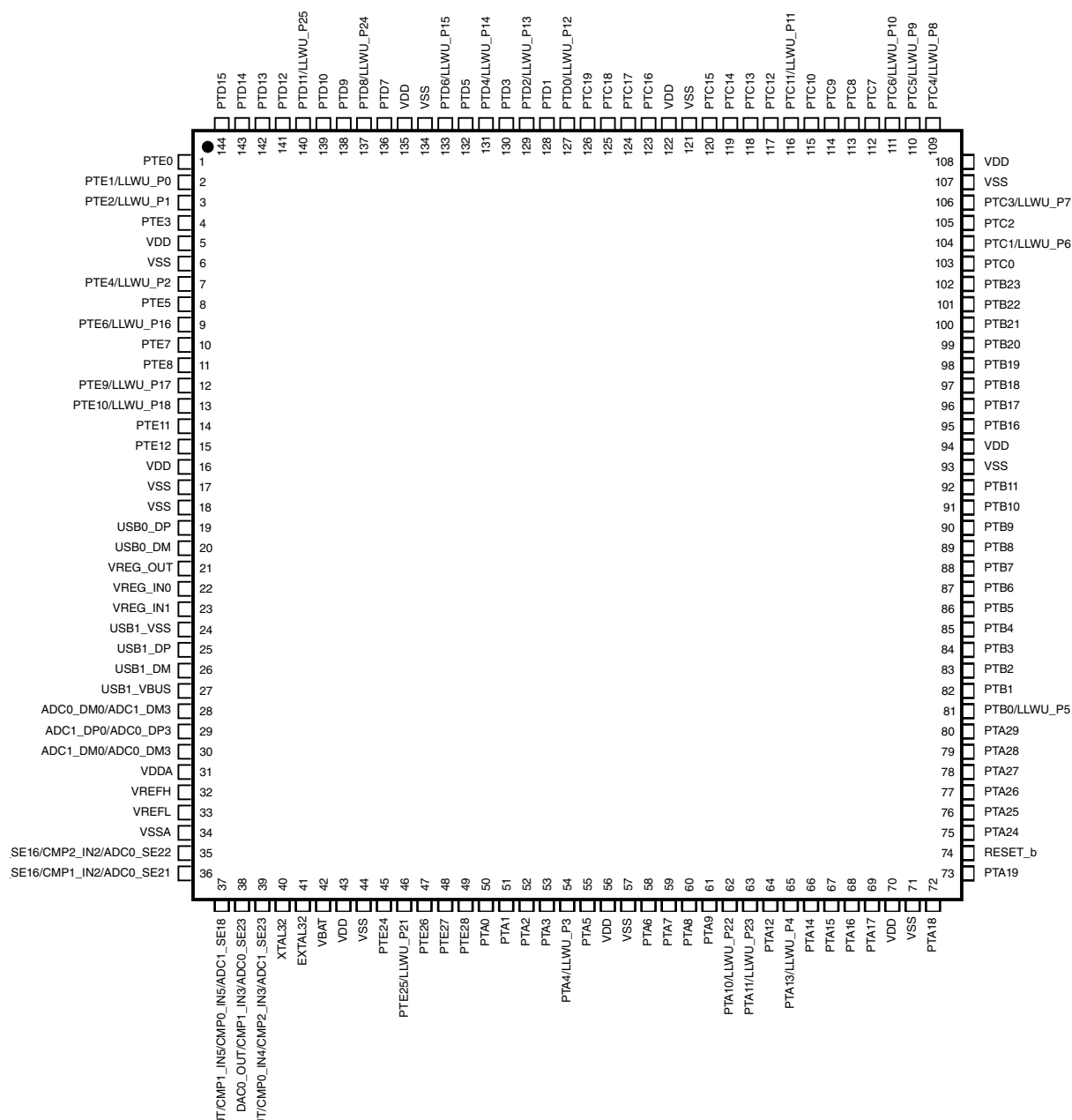


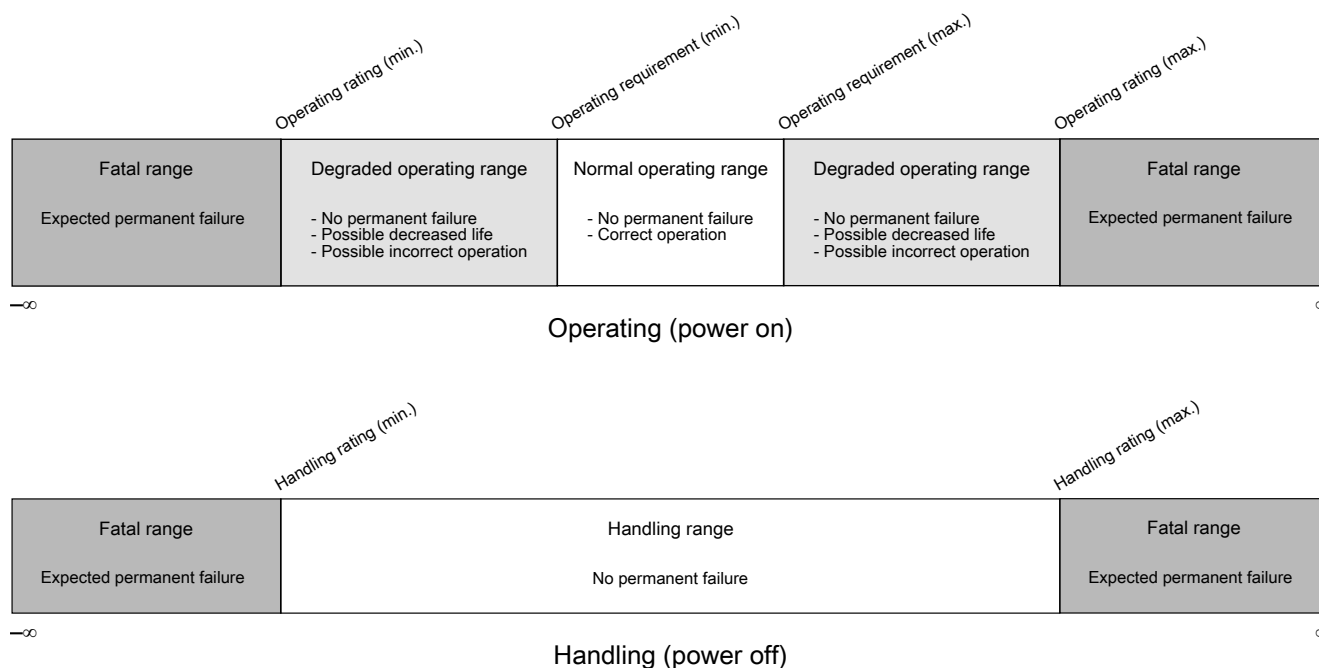
Figure 39. K66 144 LQFP Pinout Diagram

8.3 Typical-value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T_A	Ambient temperature	25	°C
V_{DD}	Supply voltage	3.3	V

8.4 Relationship between ratings and operating requirements



8.5 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip's ratings.
- During normal operation, don't exceed any of the chip's operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.